



Hi3516A DMEB DDR3 Test Report

System History



Date	Contents	Remarks
2015-01-27	The test is performed based on DDR3 1333 MHz AC150.	

注：本报告中所有测试数据为海思所测试样本的测试结果，不能代替客户的相关测试，仅供参考。



Information

Chipset	HI3516A
Board Name	Hi3516A DMEB VER.A
DRAM PartNumber	Micron MT41K256M16HA
Oscilloscope	DSA72004C DPX
Temperature	25℃
DRAM Operating Frequency	600MHz(DDR3)
VDD/Vref-CA/Vref-DQ/Vcore	1.5V/0.75V/0.75V/1.1V
DRAM_RODT	ODT OFF
SOC_RODT	ODT OFF
DRAM_ROM	40ohm
SOC_ROM	CLK:34ohm AC 2T:48ohm AC 1T:48ohm DQS:40ohm DQ:40ohm



Signal Integrity Summary & Conclusion

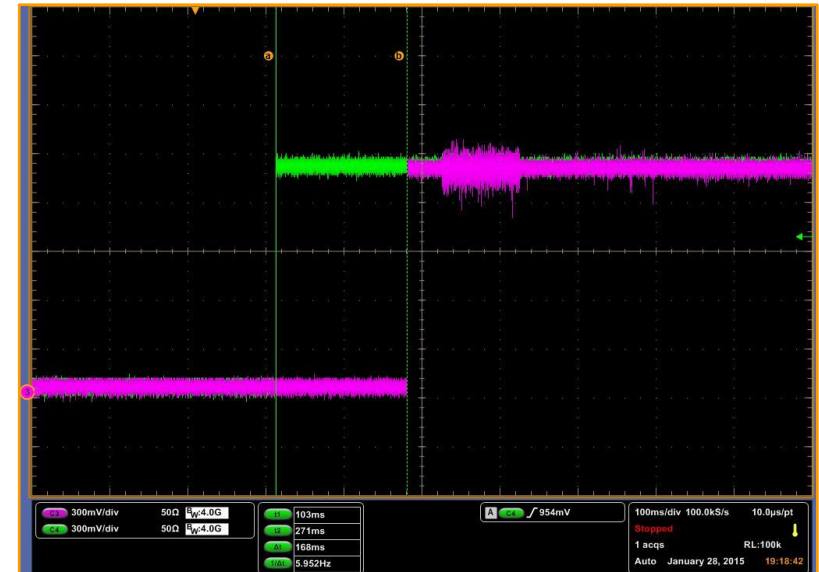
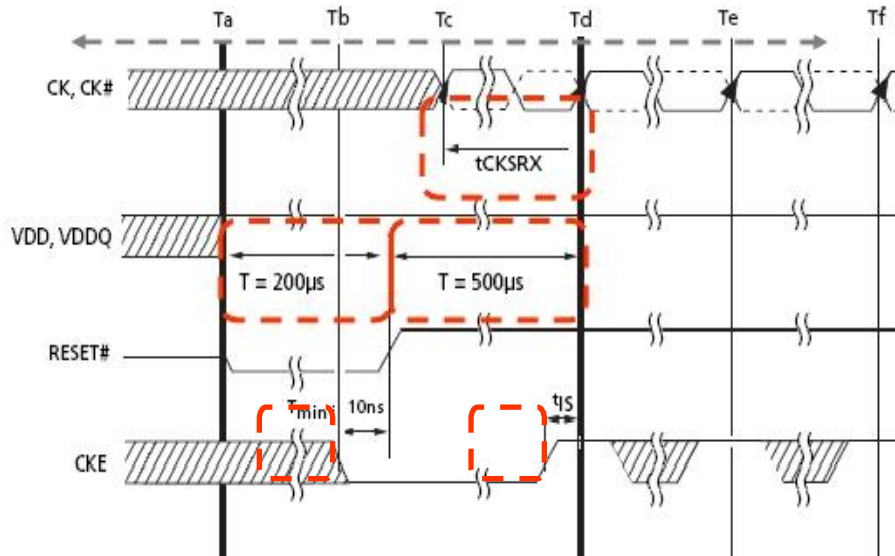
Judgment&Summary		
<p>差分时钟CLK0 Jitter (per) 余量不足, SPEC标准为$\pm 85\text{ps}$, 实测结果为$-82.57\text{ps}\sim 79.38\text{ps}$;</p> <p>(1) 从实测的AC信号时序来看, 建立保持时间余量充足;</p> <p>(2) DQ Training总窗口的余量充足;</p> <p>(3) 7x24小时高低温环境实验的结果无异常;</p> <p>综合评估: CLK0 Jitter (per) 余量不足, 风险可控。</p>		
Measurement Item	Result	Remark
Sequence Check	PASS	
Power Check	PASS	
Signal Integrity Check	Fail	CLK0 Jitter (per) 指标余量不足。

Power Up Initialization Sequence Check Result

□ SPEC

□ Stable VDD to /Reset Up

3.3.1 Power-up Initialization Sequence (Cont'd)

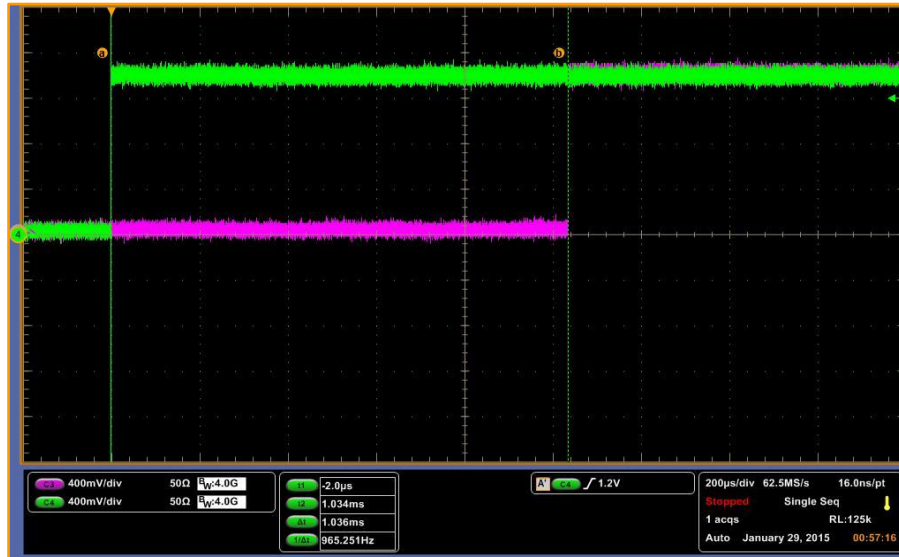


Parameter	Time	Spec	Result	Remark
Stable VDD to /Reset Up	168ms	Min:200us	PASS	/RESET needs to be maintained for minimum 200us with stable power. (JEDEC spec.)



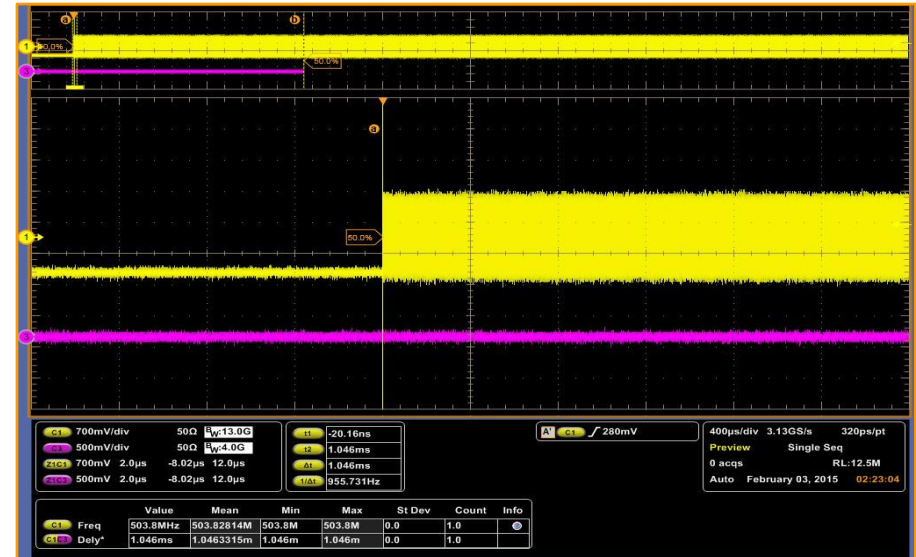
Power Up Initialization Sequence Check Result

▣ /Reset Up To CKE Up



CH3:CKE
CH4:Reset

▣ tCKSRX



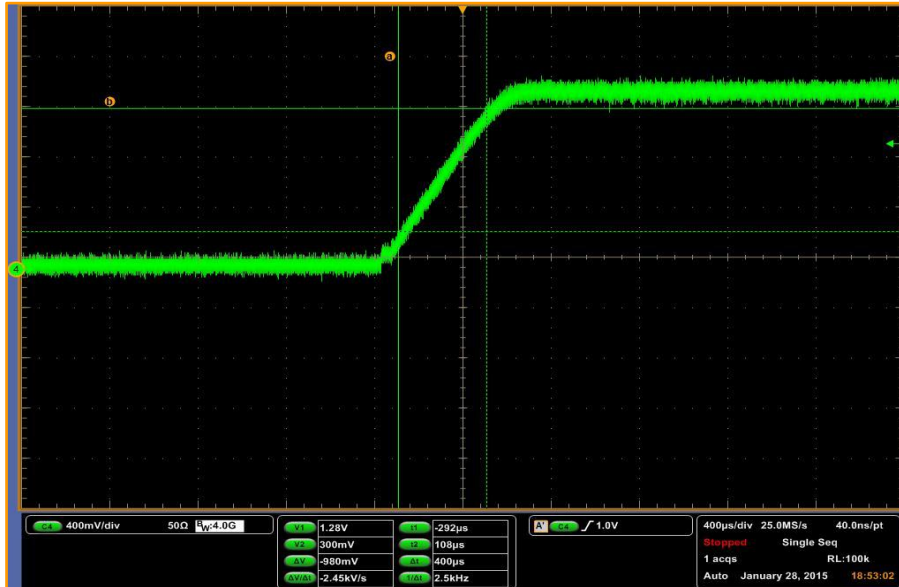
CH1:CLK
CH3:CKE

Parameter	Time	Spec	Result	Remark
/Reset Up To CKE Up	1.036ms	Min:500us	PASS	After /RESET is de-asserted. Wait for another 500us until CKE becomes active.(JEDEC spec.)
tCKSRX	1.046ms	Min:Max(5 tCK,10ns)	PASS	Clocks (CK, CK#) need to be started and stabilized for at least 10 ns or 5 tCK (which is larger) before CKE goes active.(JEDEC spec.)



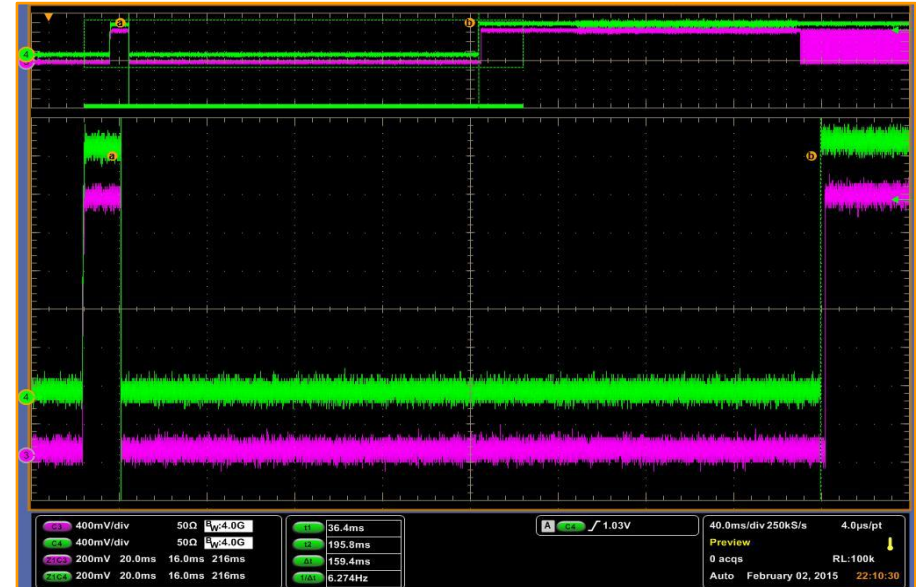
Power Up Initialization Sequence Check Result

▣ VDD Rising Time



CH4:VDD

▣ CKE Falling Edge To Reset Rising Edge



CH3:CKE

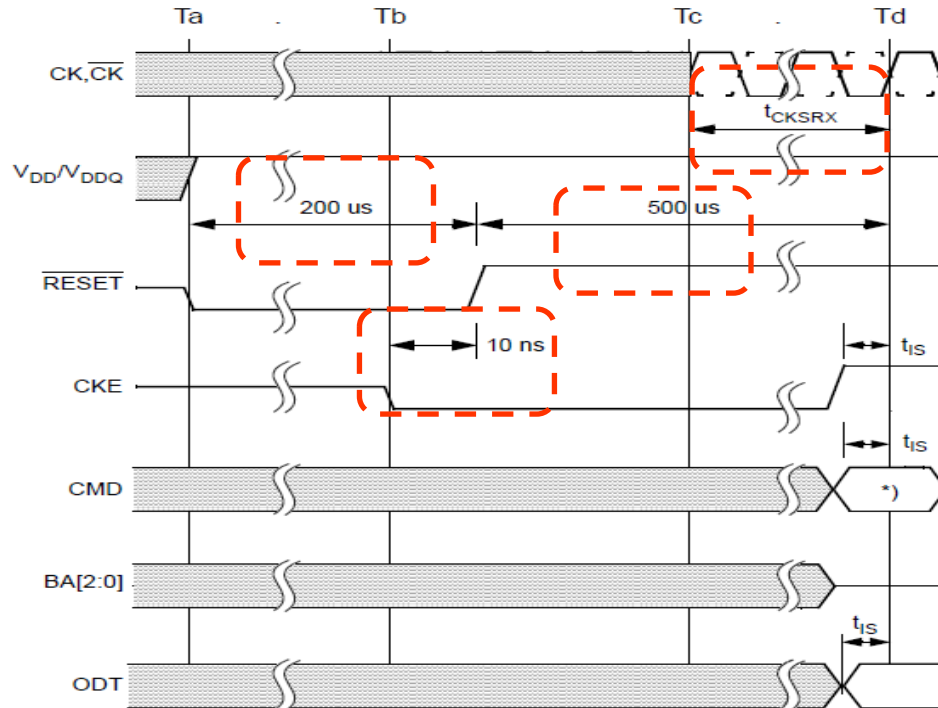
CH4:Reset

Parameter	Time	Spec	Result	Remark
VDD Rising Time	400us	Max:200ms	PASS	The power voltage ramp time between 300 mv to VDDmin must be no greater than 200 ms.(JEDEC spec.)
CKE Falling Edge to Reset Rising Edge	159.4ms	Min:10ns	PASS	CKE is pulled "Low" anytime before RESET# being de-asserted (min. time 10 ns).



Reset Initialization Sequence Check Result

▣ SPEC



▣ Reset Low Level Voltage



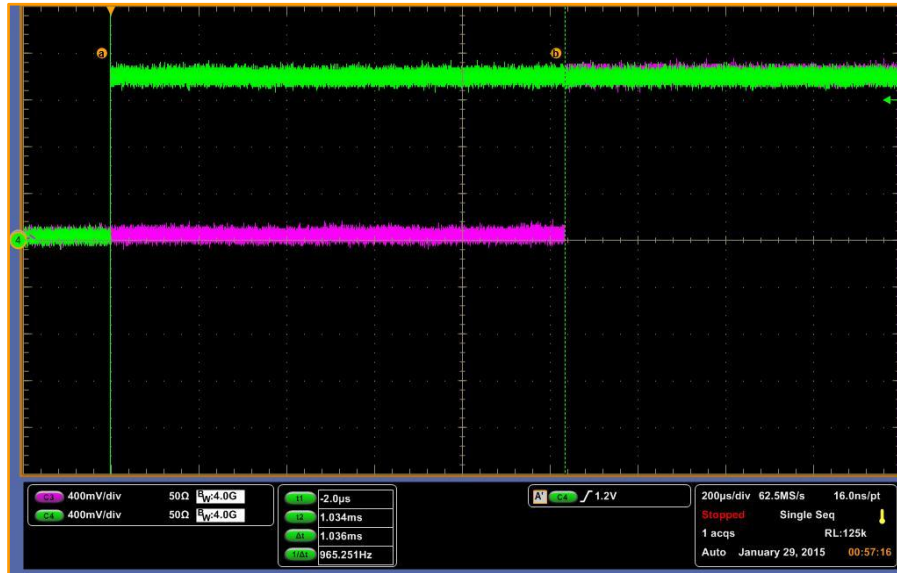
CH3: Reset

Parameter	Voltage	Spec	Result	Remark
Reset Low Level Voltage	175mV	Max:300mV	PASS	Reset Low Level Voltage must be within 300 mV.



Reset Initialization Sequence Check Result

□ /Reset Up To CKE Up



CH3:CKE
CH4:Reset

□ tCKSRX



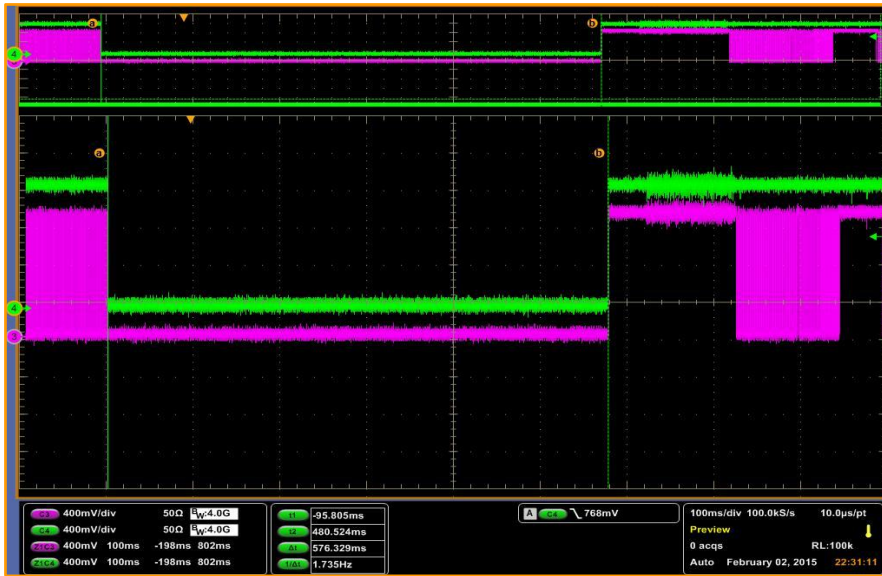
CH1:CLK
CH3:CKE

Parameter	Time	Spec	Result	Remark
/Reset Up To CKE Up	1.036ms	Min:500us	PASS	After /RESET is de-asserted. Wait for another 500us until CKE becomes active.(JEDEC spec.)
tCKSRX	1.048ms	Min:Max(5 tCK,10ns)	PASS	Clocks (CK, CK#) need to be started and stabilized for at least 10 ns or 5 tCK (which is larger) before CKE goes active.(JEDEC spec.)



Reset Initialization Sequence Check Result

▣ CKE Falling Edge To Reset Rising Edge



CH3:CKE

CH4:Reset

Parameter	Time	Spec	Result	Remark
CKE Falling Edge To Reset Rising Edge	576.3ms	Min:10ns	PASS	CKE is pulled “Low” anytime before RESET# being de-asserted (min. time 10 ns).



Average Periodic Refresh Interval Check Result

SPEC

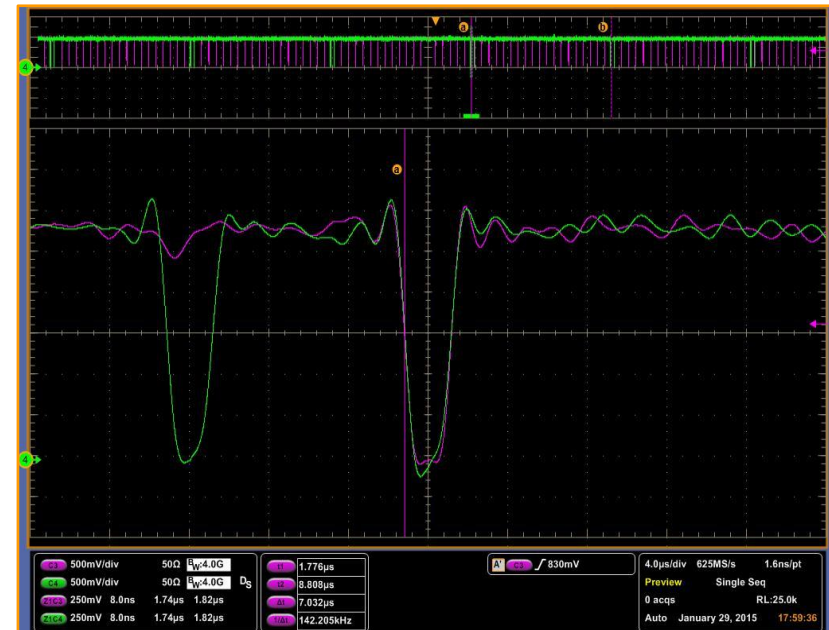
12.2 Refresh parameters by device density

Table 61 — Refresh parameters by device density

Parameter	Symbol	512Mb	1Gb	2Gb	4Gb	8Gb	Units	Notes
REF command to ACT or REF command time	tRFC	90	110	160	300	350	ns	
Average periodic refresh interval	tREFI	0 °C ≤ T _{CASE} ≤ 85 °C	7.8	7.8	7.8	7.8	μs	
		85 °C < T _{CASE} ≤ 95 °C	3.9	3.9	3.9	3.9	μs	1

NOTE 1. Users should refer to the DRAM supplier data sheet and/or the DIMM SPD to determine if DDR3 SDRAM devices support the following options or requirements referred to in this material.

Average Periodic Refresh Interval



CH3: CAS#

CH4: RAS#

Parameter	Time	Spec	Result	Remark
tREFI	7.03us	Max: 7.8us	PASS	



Power Check Result

▣ Power Noise Check Result

Parameter	Spec (mV) Vpp	Value (mV) Vpp	Result	Position	Test Point
VDD_DDR	60*	16.8	-	Hi3516A	C11
VDDIO_DDR	75*	41.6	-	Hi3516A	C42
		44.8	-	Hi3516A	C51
Vref-CA	30	24.32	PASS	DDR1	C87
		13.76	PASS	DDR2	C90
Vref-DQ	30	18.24	PASS	DDR1	C88
		15.36	PASS	DDR2	C89

***Notes:** 上述表格中，VDD_DDR和VDDIO_DDR的SPEC是海思对于Hi3516A单板设计的电源质量要求。

▣ VDDIO Supply Voltage

Parameter	Spec	Value	Result	Position	Test Point
VDDIO	1.425V~ 1.575V	1.490V	PASS	Hi3516A	C108
		1.488V	PASS	DDR1	C135
		1.489V	PASS	DDR2	C134



Signal Integrity Test Result (Clock)

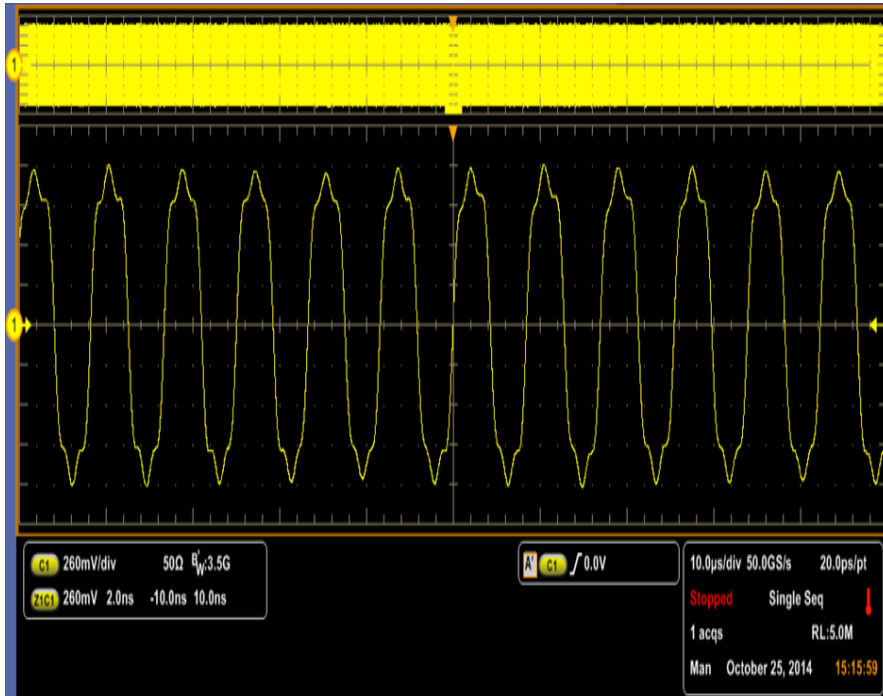
□ Clock0 Signal Integrity Test Result

Parameter	Spec(Min)	Spec(Max)	Measurement data(Min)	Measurement data(Max)	Unit	Result
Vix	-150	150	-67.33	90.94	mV	PASS
tCK(avg)	1.64	1.8	1.6827	1.6842	Ns	PASS
tCH(avg)	470	530	511.80	513.27	mtCK(avg)	PASS
tCL(avg)	470	530	486.73	488.20	mtCK(avg)	PASS
tJIT(per)	-85	85	-82.57	79.38	ps	指标临界。 时序窗口余量充足，可靠性 测试无异常出现。 风险可控。
tJIT(cc)	-170	170	-79.58	79.43	ps	PASS

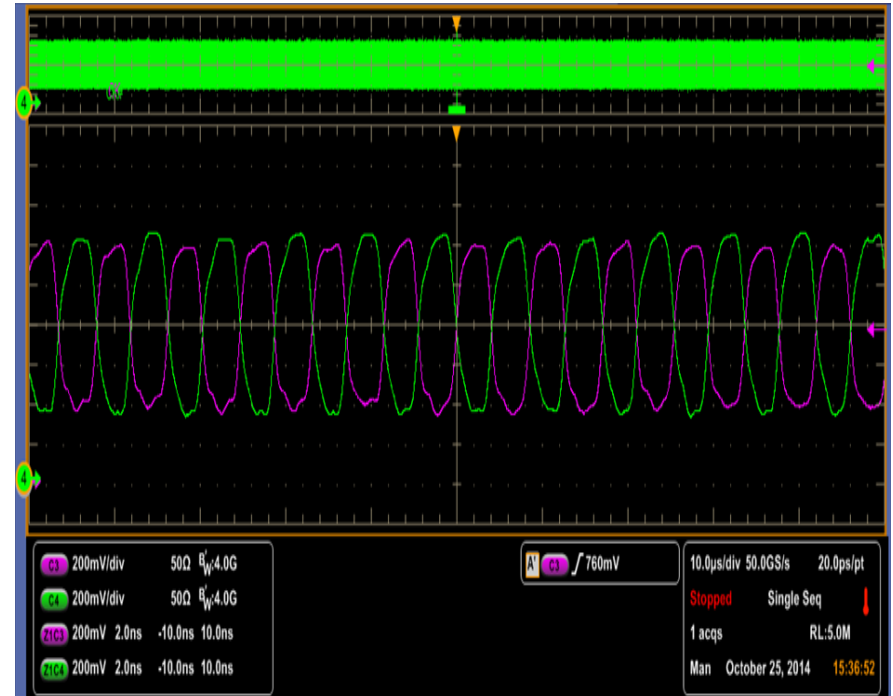
Signal Integrity Test Result (Clock)



▣ CLK0 With Differential Measurement



▣ CLK0 Vix With High Voltage Trigger





Signal Integrity Test Result (Clock)

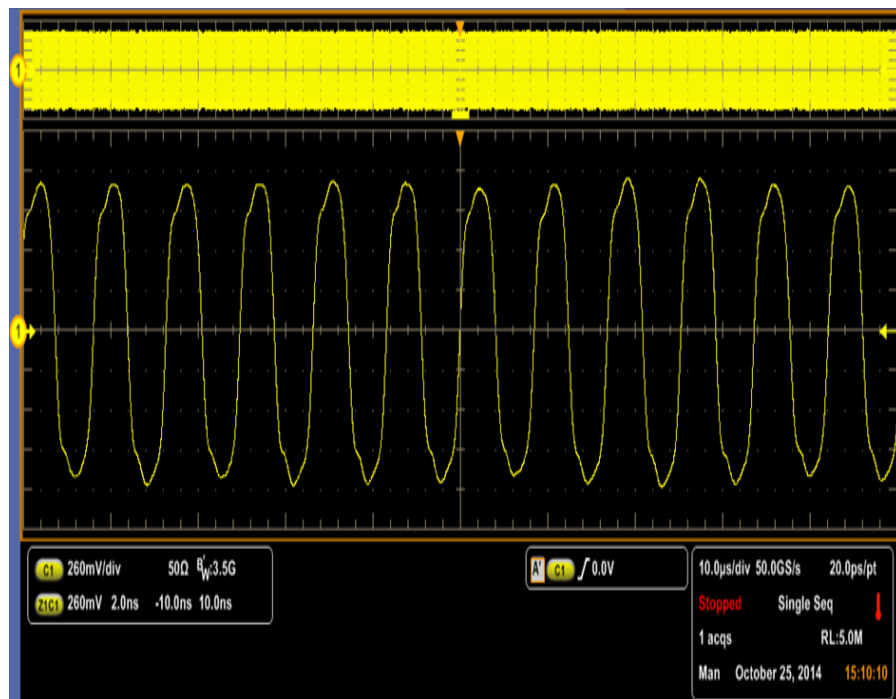
▣ Clock1 Signal Integrity Test Result

Parameter	Spec(Min)	Spec(Max)	Measurement data(Min)	Measurement data(Max)	Unit	Result
Vix	-150	150	-75.33	138	mV	PASS
tCK(avg)	1.64	1.8	1.6829	1.6842	ns	PASS
tCH(avg)	470	530	478.34	480.33	mtCK(avg)	PASS
tCL(avg)	470	530	519.63	521.66	mtCK(avg)	PASS
tJIT(per)	-85	85	-76.23	75.07	ps	PASS
tJIT(cc)	-170	170	-79.25	78.48	ps	PASS

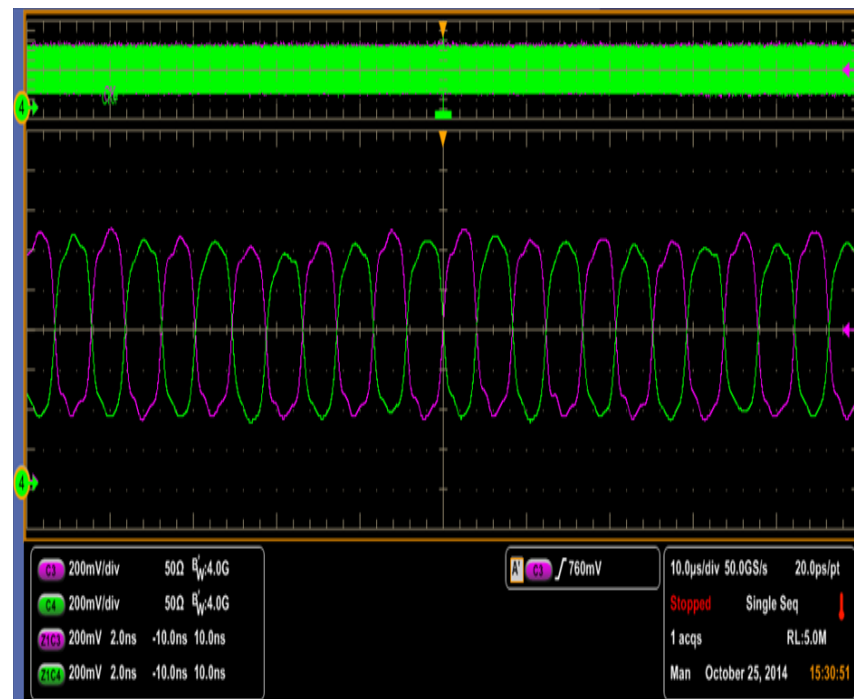
Signal Integrity Test Result (Clock)



▣ CLK1 With Differential Measurement



▣ CLK1 Vix With High Voltage Trigger





Signal Integrity Test Result (CMD&ADDR)

■ SPEC

Table 70 — ADD/CMD Setup and Hold Base-Values for 1V/ns

Symbol	Reference	DDR3-800	DDR3-1066	DDR3-1333	DDR3-1600	DDR3-1866	DDR3-2133	Units
tIS(base) AC175	V _{IH/L(ac)}	200	125	65	45	-	-	ps
tIS(base) AC150	V _{IH/L(ac)}	350	275	190	170	-	-	ps
tIS(base) AC135	V _{IH/L(ac)}	-	-	-	-	65	60	ps
tIS(base) AC125	V _{IH/L(ac)}	-	-	-	-	150	135	ps
tIH(base) DC100	V _{IH/L(dc)}	275	200	140	120	100	95	ps

$\Delta tIS, \Delta tIH$ derating in [ps] AC/DC based Alternate AC150 Threshold $\rightarrow V_{IH(ac)} = V_{REF(dc)} + 150mV, V_{IL(ac)} = V_{REF(dc)} - 150mV$																	
		CK,CK# Differential Slew Rate															
		4.0 V/ns		3.0 V/ns		2.0 V/ns		1.8 V/ns		1.6 V/ns		1.4 V/ns		1.2 V/ns		1.0 V/ns	
		ΔtIS	ΔtIH	ΔtIS	ΔtIH	ΔtIS	ΔtIH	ΔtIS	ΔtIH	ΔtIS	ΔtIH	ΔtIS	ΔtIH	ΔtIS	ΔtIH	ΔtIS	ΔtIH
CMD/ ADD Slew rate V/ns	2.0	75	50	75	50	75	50	83	58	91	66	99	74	107	84	115	100
	1.5	50	34	50	34	50	34	58	42	66	50	74	58	82	68	90	84
	1.0	0	0	0	0	0	0	8	8	16	16	24	24	32	34	40	50
	0.9	0	-4	0	-4	0	-4	8	4	16	12	24	20	32	30	40	46
	0.8	0	-10	0	-10	0	-10	8	-2	16	6	24	14	32	24	40	40
	0.7	0	-16	0	-16	0	-16	8	-8	16	0	24	8	32	18	40	34
	0.6	-1	-26	-1	-26	-1	-26	7	-18	15	-10	23	-2	31	8	39	24
	0.5	-10	-40	-10	-40	-10	-40	-2	-32	6	-24	14	-16	22	-6	30	10
	0.4	-25	-60	-25	-60	-25	-60	-17	-52	-9	-44	-1	-36	7	-26	15	-10



Signal Integrity Test Result (CMD&ADDR)

▣ 1T Command Signal Integrity Test Result

CMD /ADD	Input SetupTime (tIS)@AC150 tIS(min)	Input Hold Time (tIH)@DC100 tIH(min)	Units	Remaik
Spec	265	190	ps	
CLK0_CS0N	798.99	609.97	ps	PASS
CLK0_ODT0	871.24	635.77	ps	PASS
CLK0_CKE	761.09	693.22	ps	PASS
CLK1_CS1N	801.34	587.02	ps	PASS
CLK1_ODT1	784.91	635.06	ps	PASS
CLK1_CKE	791.11	647.22	ps	PASS

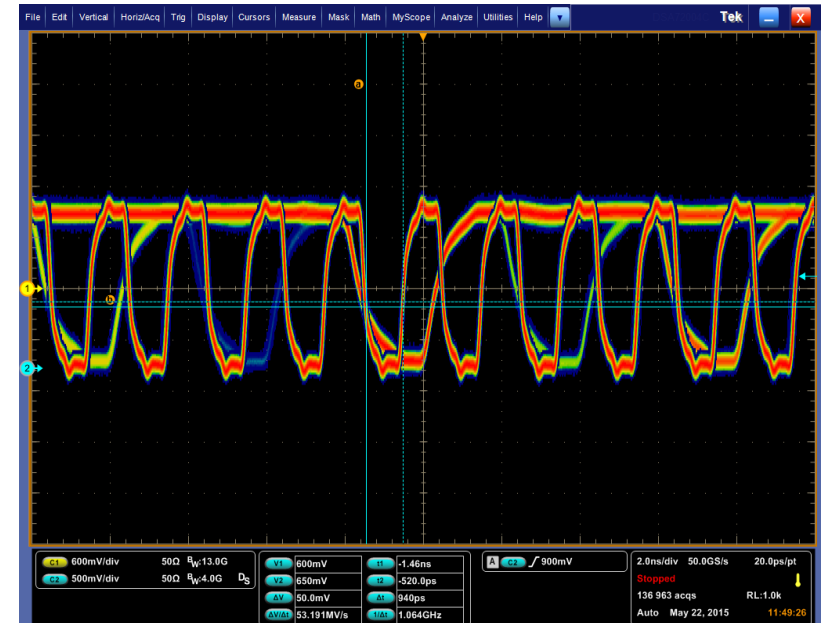


Signal Integrity Test Result (CMD&ADDR)

1T_CSN Wave



CLK0_CS

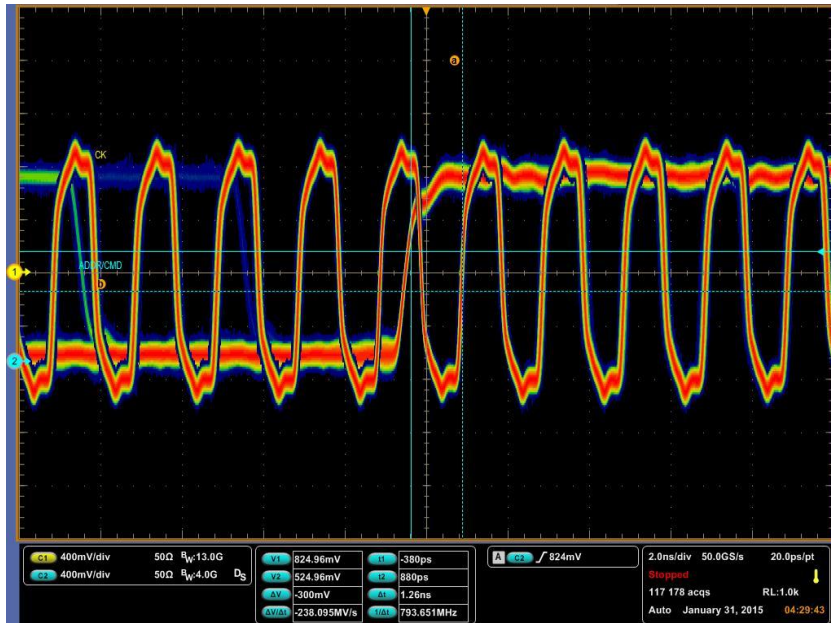


CLK1_CS



Signal Integrity Test Result (CMD&ADDR)

▣ 1T_ODT Wave



CLK0_ODT



CLK1_ODT



Signal Integrity Test Result (CMD&ADDR)

▣ 1T_CKE Wave



CLK0_CKE

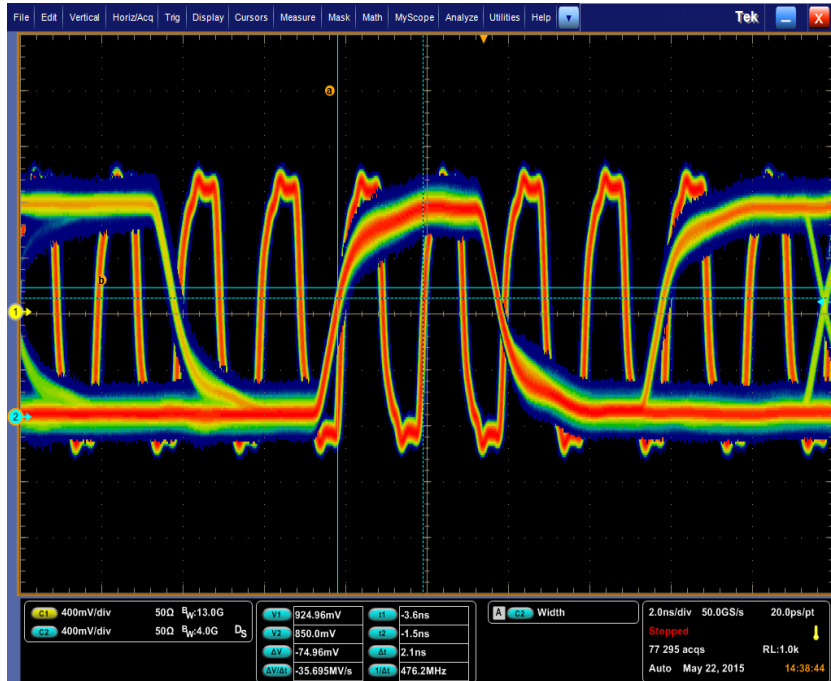


CLK1_CKE



Signal Integrity Test Result (CMD&ADDR)

2T_A7 Wave



2T_CAS Wave





Signal Integrity Test Result (DATA)

□ SPEC

Table 76 — Data Setup and Hold Base-Values

Symbol	Reference	DDR3-800	DDR3-1066	DDR3-1333	DDR3-1600	DDR3-1866	DDR3-2133	Units	Notes
tDS(base) AC175	$V_{IH/L(ac)}$ SR=1V/ns	75	25	-	-	-	-	ps	2
tDS(base) AC150	$V_{IH/L(ac)}$ SR=1V/ns	125	75	30	10	-	-	ps	2
tDS(base) AC135	$V_{IH/L(ac)}$ SR=1V/ns	165	115	60	40			ps	2, 3
tDS(base) AC135	$V_{IH/L(ac)}$ SR=2V/ns	-	-	-	-	68	53	ps	1
tDH(base) DC100	$V_{IH/L(dc)}$ SR=1V/ns	150	100	65	45	-	-	ps	2
tDH(base)DC100	$V_{IH/L(dc)}$ SR=2V/ns					70	55	ps	1
NOTE 1. (ac/dc referenced for 2V/ns DQ-slew rate and 4V/ns DQS slew rate)									
NOTE 2. (ac/dc referenced for 1V/ns DQ-slew rate and 2V/ns DQS slew rate)									
NOTE 3. Optional in DDR3 SDRAM									

Table 78 — Derating values for DDR3-800/1066/1333/1600 tDS/tDH - (AC150)Derating

ΔtDS, ΔtDH derating in [ps] AC/DC based ¹																	
		DQS, DQS# Differential Slew Rate															
		4.0 V/ns		3.0 V/ns		2.0 V/ns		1.8 V/ns		1.6 V/ns		1.4 V/ns		1.2 V/ns		1.0 V/ns	
		ΔtDS	ΔtDH	ΔtDS	ΔtDH	ΔtDS	ΔtDH	ΔtDS	ΔtDH	ΔtDS	ΔtDH	ΔtDS	ΔtDH	ΔtDS	ΔtDH	ΔtDS	ΔtDH
DQ Slew rate V/ns	2.0	75	50	75	50	75	50	-	-	-	-	-	-	-	-	-	-
	1.5	50	34	50	34	50	34	58	42	-	-	-	-	-	-	-	-
	1.0	0	0	0	0	0	0	8	8	16	16	-	-	-	-	-	-
	0.9	-	-	0	-4	0	-4	8	4	16	12	24	20	-	-	-	-
	0.8	-	-	-	-	0	-10	8	-2	16	6	24	14	32	24	-	-
	0.7	-	-	-	-	-	-	8	-8	16	0	24	8	32	18	40	34
	0.6	-	-	-	-	-	-	-	-	15	-10	23	-2	31	8	39	24
	0.5	-	-	-	-	-	-	-	-	-	-	14	-16	22	-6	30	10
	0.4	-	-	-	-	-	-	-	-	-	-	-	-	7	-26	15	-10

NOTE 1. Cell contents shaded in red are defined as 'not supported'.



Signal Integrity Test Result (DATA)

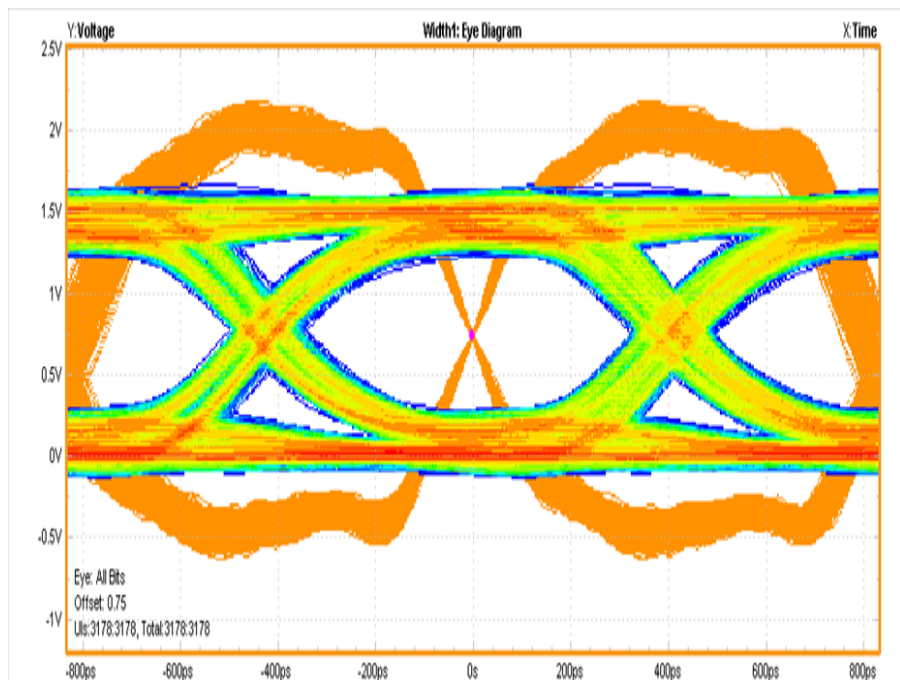
▣ Data Signal Integrity Test Result

Parameter			Spec	DQ3	DQ10	DQ22	DQ28	Unit	Result
Data	Write	Input Setup-Time(tDS)@AC150 [tDS(base)=30ps]	min:105	273.71	290.84	248.22	226.51	ps	PASS
		Input Hold-Time(tDH)@DC100 [tDH(base)=65ps]	min:115	279.22	291.51	319.94	321.60	ps	PASS

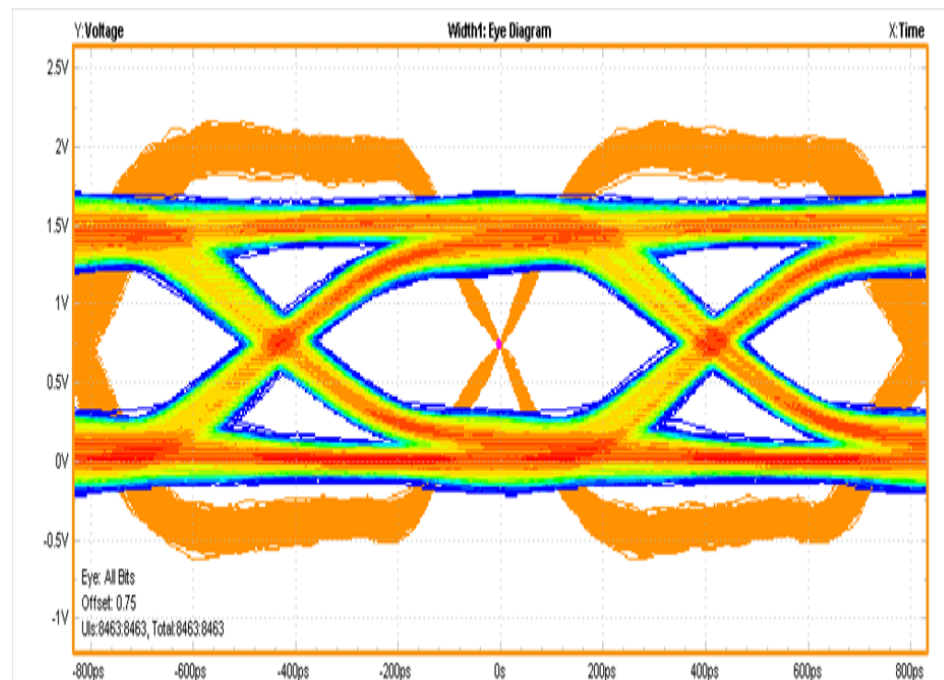
Signal Integrity Test Result (DATA)



▣ DQ3_write



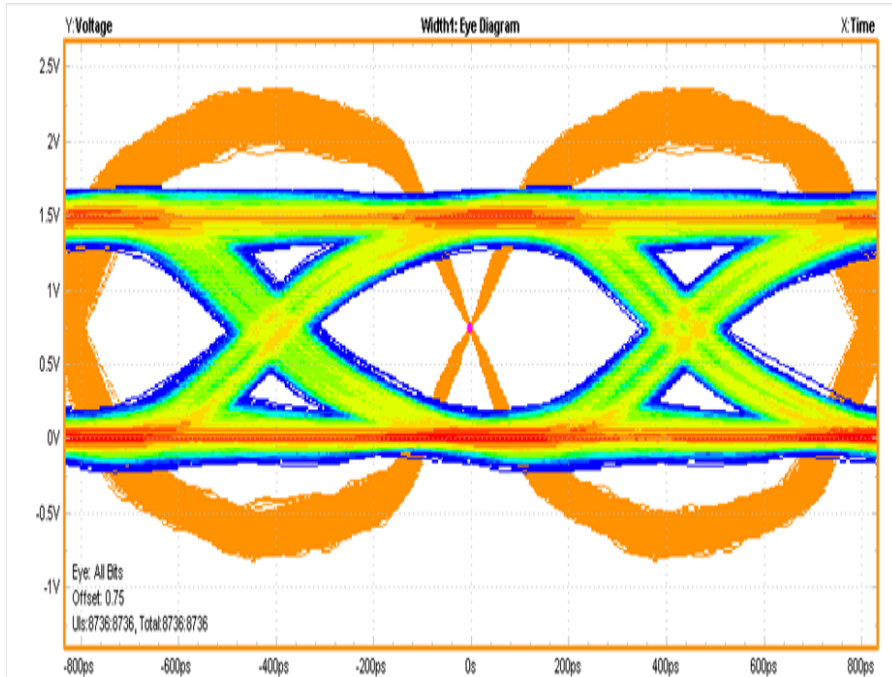
▣ DQ10_write



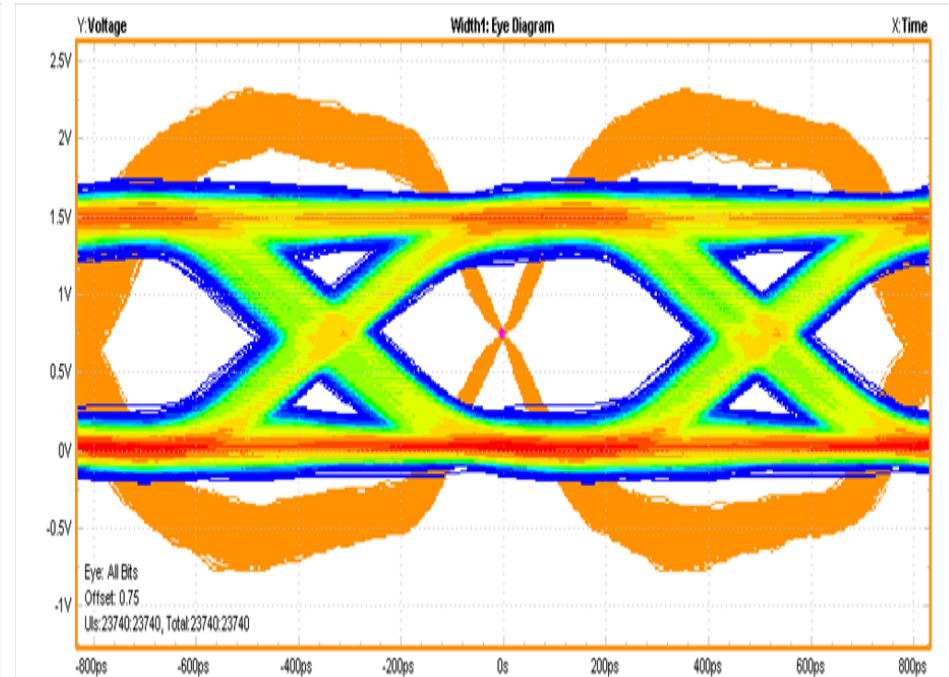


Signal Integrity Test Result (DATA)

▣ DQ22_write



▣ DQ28_write





```
## DDR training terminated.  
Boot Training result. The write window of prebit-deskew
```

[illegible]



DQ	0	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23	24	25	26	27	28	29	30	31	HEX_VALUE	DQS	DQ	WIN
0	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	X	X	X	0x3fffffff	27	13	26
1	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	X	0xffffffff	27	14	28
2	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	0x1fffffff	27	14	29
3	X	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	0x7fffffff	27	16	30
4	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	X	0xffffffff	27	14	28
5	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	X	X	0x7fffffff	27	13	27
6	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	X	X	0x7fffffff	27	13	27
7	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	0x1fffffff	27	14	29
8	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	X	X	0x7fffffff	29	13	27
9	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	X	X	X	X	0x1fffffff	29	12	25
10	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	X	0xffffffff	29	14	28
11	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	X	X	X	X	0x1fffffff	29	12	25
12	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	X	X	X	X	0x1fffffff	29	12	25
13	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	X	X	X	X	0x1fffffff	29	12	25
14	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	X	X	X	0x3fffffff	29	13	26
15	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	X	X	X	X	0x1fffffff	29	12	25
16	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	X	X	0x7fffffff	27	13	27
17	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	X	0xffffffff	27	14	28
18	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	X	X	X	0x1fffffff	27	14	29
19	-	-																																		



Thank you